

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	50	((("5232569") or ("4916496") or ("5290323") or ("5433823") or ("5766446") or ("4385102") or ("4449285") or ("4478690") or ("4483694") or ("4555453") or ("4563806") or ("4576830") or ("4620772") or ("4761357") or ("4843451") or ("5017828") or ("5196725") or ("5196907") or ("5229313") or ("5230849") or ("5347766") or ("5493102") or ("5578503") or ("5625587") or ("5897790") or ("5925891") or ("6239005") or ("4258242") or ("4287383") or ("4305111") or ("4359488") or ("4365283") or ("4438188") or ("4447825") or ("4517227") or ("4538158") or ("4596722") or ("4596635") or ("4615908") or ("4756756") or ("4853346") or ("4910538") or ("4915978") or ("4962054") or ("4965090") or ("4968319") or ("4980306") or ("5007424") or ("5019469") or ("5019748"))). PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/03/05 12:25
L2	10067	(438/149,151,157,161 or 257/40,57,384).ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/05 12:27
L3	4986	L2 and @ad<"20030712"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/05 12:27
L4	2331	L3 and (tft or (thin film transistor))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/05 12:27
L5	924	L4 and ((dielectric or insulating) with layer with substrate with gate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/05 12:27

L6	48	L5 and (coplanar with tft)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/05 12:28
L7	61	L5 and (coplanar with (tft or transistor))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/05 12:28
S1	40	((JOHN) near2 (RUDIN)).INV.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/04 15:19
S2	2	((("5183780") or ("6326640")).PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/03/04 15:24
S3	24	("4234356"   "4400715"   "4542580"   "4651410").PN. OR ("5183780").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/04 15:27
S4	44	("4106951"   "5468519"   "5500537").PN. OR ("6326640").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/04 15:31
S5	19	("20010029098"   "20020022299"   "20020155729"   "20020164835"   "20030170937"   "5567550"   "5574291"   "5677041"   "5691089"   "5705826"   "5942374"   "5946551"   "6207472"   "6300988"   "6326640"   "6429457"   "6452207"   "6528816").PN. OR ("7015502").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/04 15:33
S6	19	("5708130"   "5962631"   "6107452"   "6169163"   "6204515"   "6372154").PN. OR ("6452207").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/04 15:36
S8	12	("20020045289"   "20020086464"   "20020093017"   "20030059984"   "20030092232"   "20030108727"   "20030211665"   "3990926"   "5388328"   "6335539"   "6344660"   "6555411").PN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/04 15:40
S9	48	("5693977"   "6060338"   "6107117").PN. OR ("6335539").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/04 15:42
S10	27	S9 and @ad<"20030712"	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/03/04 15:43

S13	10054	(438/149,151,157,161 or 257/40,57,384).ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/04 16:18
S14	4986	S13 and @ad<"20030712"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/04 16:18
S15	2331	S14 and (tft or (thin film transistor))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/04 16:18
S16	232	S15 and ((organic with (semiconductor or channel)) and ((resin or epoxy or flexible) with substrate))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/04 16:19
S17	10	S15 and (electrolytic with deposit\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/04 16:20
S18	266	(tft or (thin film transistor)) and (source with drain with gate with layer with ("same" and common))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/04 17:00
S19	129	S18 and @ad<"20030712"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/04 17:00
S20	555	(tft or (thin film transistor)) and ((electrolytic with deposit \$3) or (electro-deposit\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/04 20:39
S21	231	S20 and @ad<"20030712"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/03/04 20:40

**3/ 5/ 2009 12:28:56 PM**

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electrodes in layers\ EAST search TFT w electrodes in layers.wsp**